

International
IR Rectifier

Data Sheet No. PD60299

IRS212(7, 71, 8, 81)(S)PbF

CURRENT SENSING SINGLE CHANNEL DRIVER

Features

- Floating channel designed for bootstrap operation
Fully operational to +600 V
Tolerant to negative transient voltage dV/dt immune
- Application-specific gate drive range:
Motor Drive: 12 V to 20 V (IRS2127/IRS2128)
Automotive: 9 V to 20 V (IRS21271/IRS21281)
- Undervoltage lockout
- 3.3 V, 5 V, and 15 V input logic compatible
- FAULT lead indicates shutdown has occurred
- Output in phase with input (IRS2127/IRS21271)
- Output out of phase with input (IRS2128/IRS21281)
- RoHS compliant

Description

The IRS2127/IRS2128/IRS21271/IRS21281 are high voltage, high speed power MOSFET and IGBT drivers. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL outputs, down to 3.3 V. The protection circuitry detects over-current in the driven power transistor and terminates the gate drive voltage. An open drain FAULT signal is provided to indicate that an over-current shutdown has occurred. The output driver features a high pulse current buffer stage designed for minimum cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side or low-side configuration which operates up to 600 V.

Product Summary

V_{OFFSET}	600 V max.
I_{O+/-}	200 mA / 420 mA
V_{OUT}	12 V - 20V 9 V - 20 V (IRS2127/IR2128) (IRS21271/IR21281)
V_{Csth}	250 mV or 1.8 V
t_{on/off} (typ.)	150 ns & 150 ns

Packages

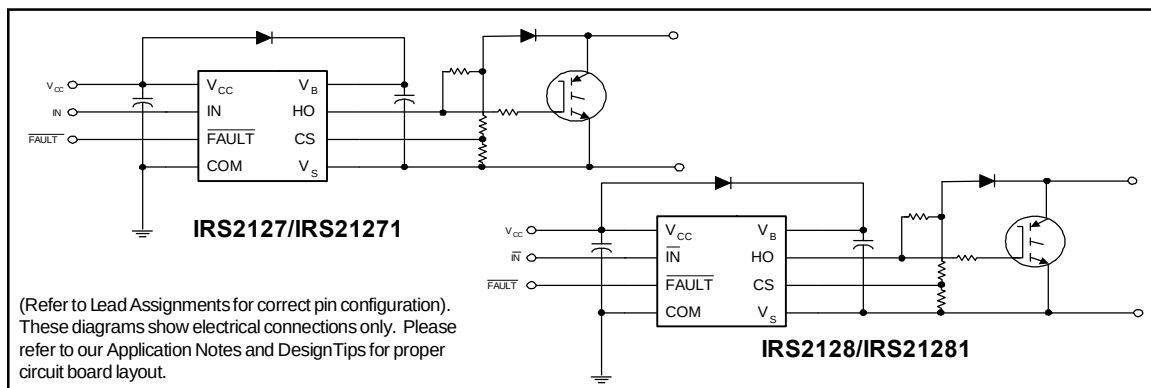


8-Lead PDIP



8-Lead SOIC

Typical Connection



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition		Min.	Max.	Units
V _B	High-side floating supply voltage		-0.3	625	V
V _S	High-side floating offset voltage		V _B - 25	V _B + 0.3	
V _{HO}	High-side floating output voltage		V _S - 0.3	V _B + 0.3	
V _{CC}	Logic supply voltage		-0.3	25	
V _{IN}	Logic input voltage		-0.3	V _{CC} + 0.3	
V _{FLT}	$\overline{\text{FAULT}}$ output voltage		-0.3	V _{CC} + 0.3	
V _{CS}	Current sense voltage		V _S - 0.3	V _B + 0.3	
dV _S /dt	Allowable offset supply voltage transient		—	50	V/ns
P _D	Package power dissipation @ TA ≤ +25 °C	8-Lead DIP	—	1.0	W
		8-Lead SOIC	—	0.625	
R _{thJA}	Thermal resistance, junction to ambient	8-Lead DIP	—	125	°C/W
		8-Lead SOIC	—	200	
T _J	Junction temperature		—	150	°C
T _S	Storage temperature		-55	150	
T _L	Lead temperature (soldering, 10 seconds)		—	300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in Fig. 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15 V differential.

Symbol	Definition		Min.	Max.	Units
V _B	High-side floating supply voltage	(IRS2127/IRS2128)	V _S + 12	V _S + 20	V
		(IRS21271/IRS21281)	V _S + 9	V _S + 20	
V _S	High-side floating offset voltage		Note 1	600	
V _{HO}	High-side floating output voltage		V _S	V _B	
V _{CC}	Logic supply voltage		10	20	
V _{IN}	Logic input voltage		0	V _{CC}	
V _{FLT}	FAULT output voltage		0	V _{CC}	
V _{CS}	Current sense signal voltage		V _S	V _S + 5	
T _A	Ambient temperature		-40	125	

Note 1: Logic operational for V_S of -5 V to +600 V. Logic state held for V_S of -5 V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15 V, C_L = 1000 pF and T_A = 25 °C unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Fig. 3.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	150	200	ns	$V_S = 0$ V
t_{off}	Turn-off propagation delay	—	150	200		$V_S = 600$ V
t_r	Turn-on rise time	—	80	130		
t_f	Turn-off fall time	—	40	65		
t_{bl}	Start-up blanking time	550	750	950		
t_{cs}	CS shutdown propagation delay	—	65	360		
t_{ft}	CS to FAULT pull-up propagation delay	—	270	510		

Static Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15 V and T_A = 25 °C unless otherwise specified. The V_{IN} , V_{TH} , and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to V_S .

Symbol	Definition		Min.	Typ.	Max.	Units	Test Conditions
V _{IH}	Logic “1” input voltage	(IRS2127/IRS21271)	2.5	—	—	V	V _{CC} = 10 V to 20 V
	Logic “0” input voltage	(IRS2128/IRS21281)					
V _{IL}	Logic “0” input voltage	(IRS2127/IRS21271)	—	—	0.8		
	Logic “1” input voltage	(IRS2128/IRS21281)					
V _{CSTH+}	CS input positive going threshold	(IRS2127/IRS2128)	180	250	320	mV	
		(IRS21271/IRS21281)	1.5	1.8	2.1	V	
V _{OH}	High level output voltage, V _{BIAS} - V _O		—	0.05	0.2		
V _{OL}	Low level output voltage, V _O		—	0.02	0.1		
I _{LK}	Offset supply leakage current		—	—	50	µA	V _B = V _S = 600 V
I _{QBS}	Quiescent V _{BS} supply current		—	300	800		V _{IN} = 0 V or 5 V
I _{QCC}	Quiescent V _{CC} supply current		—	60	120		V _{IN} = 5 V
I _{IN+}	Logic “1” input bias current		—	7.0	15		V _{IN} = 0 V
I _{IN-}	Logic “0” input bias current		—	—	5.0		V _{CS} = 3 V
I _{CS+}	“High” CS bias current		—	—	5.0		V _{CS} = 0 V
I _{CS-}	“High” CS bias current		—	—	5.0		
V _{BSUV+}	V _{BS} supply undervoltage positive going threshold	(IRS2127/IRS2128)	8.8	10.3	11.8		V
		(IRS21271/IRS21281)	6.3	7.2	8.2		
V _{BSUV-}	V _{BS} supply undervoltage negative going threshold	(IRS2127/IRS2128)	7.5	9.0	10.6	mA	
		(IRS21271/IRS21281)	6.0	6.8	7.7		
I _{O+}	Output high short circuit pulsed current		200	290	—	Ω	V _O = 0 V, V _{IN} = 5 V PW ≤ 10 µs
I _{O-}	Output low short circuit pulsed current		420	600	—		V _O = 15 V, V _{IN} = 0 V PW ≤ 10 µs
R _{on,FLT}	FAULT - low on resistance		—	125	—		



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Lead Definitions

Symbol	Description
V _{CC}	Logic and gate drive supply
IN	Logic input for gate driver output (HO), in phase with HO (IRS2127/IRS21271) out of phase with HO (IRS2128/IRS21281)
FAULT	Indicates over-current shutdown has occurred, negative logic
COM	Logic ground
V _B	High-side floating supply
HO	High-side gate drive output
V _S	High-side floating supply return
CS	Current sense input to current sense comparator

Lead Assignments

8 Lead PDIP IRS2127/IRS21271	8 Lead SOIC IRS2127S/IRS21271S
8 Lead PDIP IRS2128/IRS21281	8 Lead SOIC IRS2128S/IRS21281S

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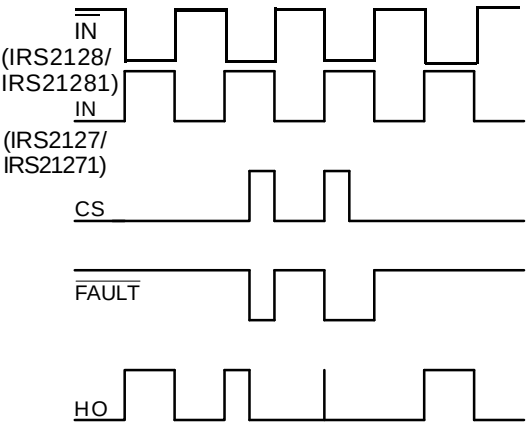


Figure 1. Input/Output Timing Diagram

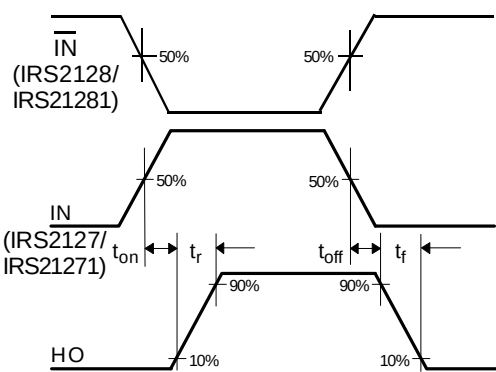


Figure 2. Switching Time Waveform Definition

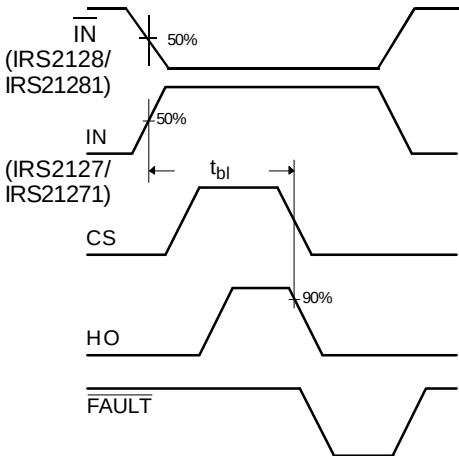


Figure 3. Start-Up Blanking Time Waveform Definitions

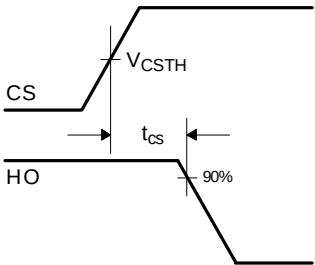


Figure 4. CS Shutdown Waveform Definitions

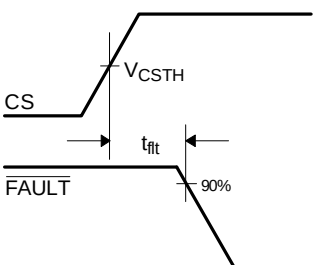


Figure 5. CS to FAULT Waveform Definitions

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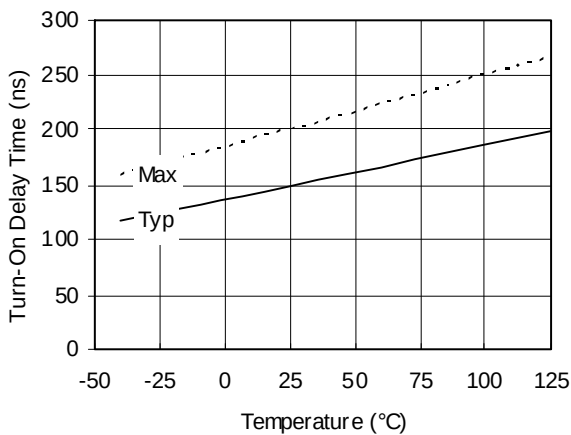


Figure 6A. Turn-On Delay Time vs. Temperature

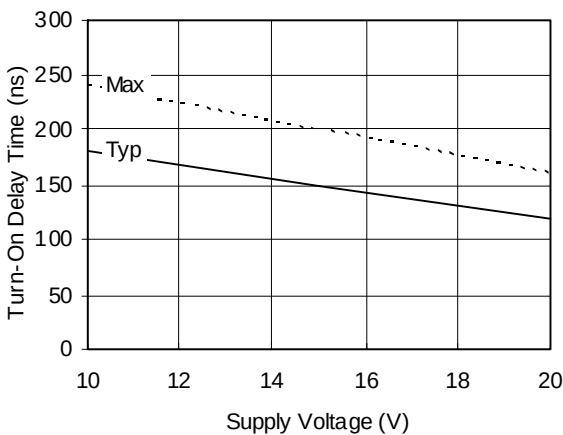


Figure 6B. Turn-On Delay Time vs. Voltage

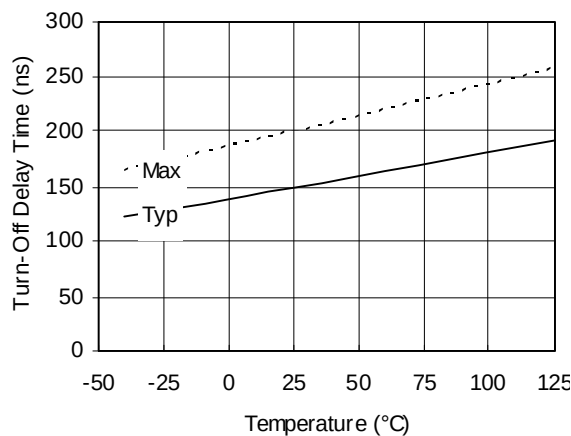


Figure 7A. Turn-Off Delay Time vs. Temperature

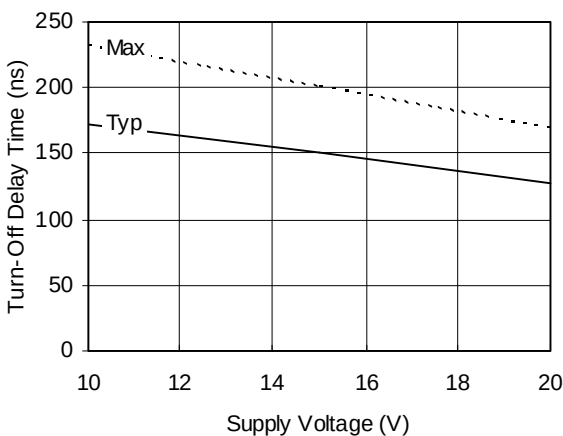


Figure 7B. Turn-Off Delay Time vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

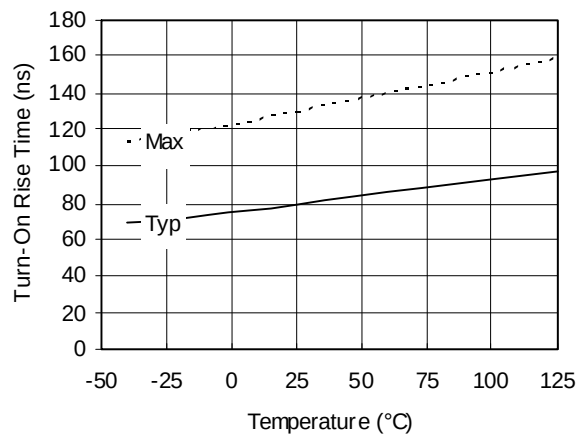


Figure 8A. Turn-On Rise Time vs. Temperature

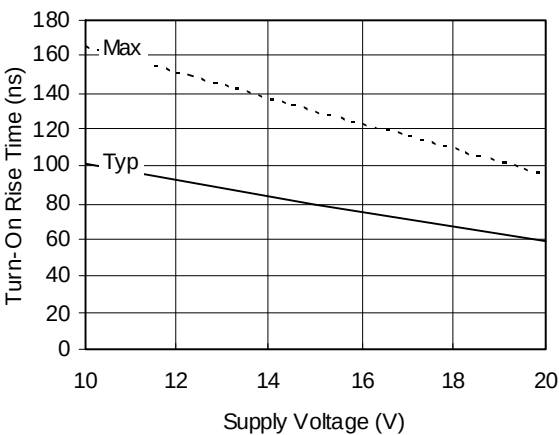


Figure 8B. Turn-On Rise Time vs. Voltage

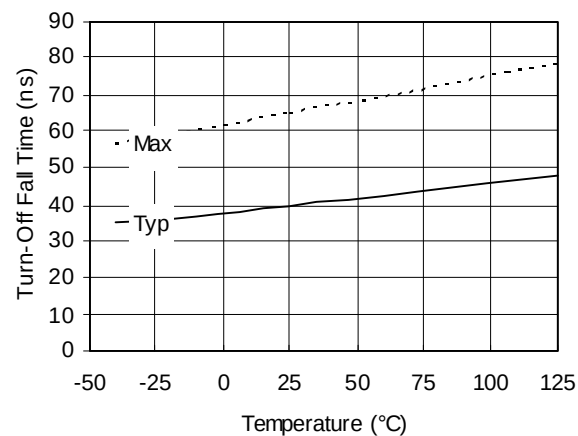


Figure 9A. Turn-Off Fall Time vs. Temperature

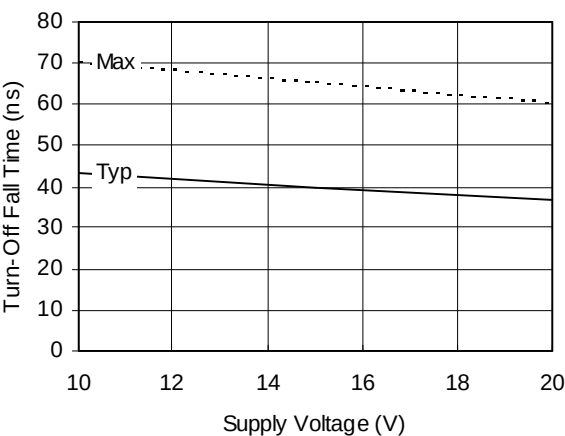


Figure 9B. Turn-Off Fall Time vs. Voltage

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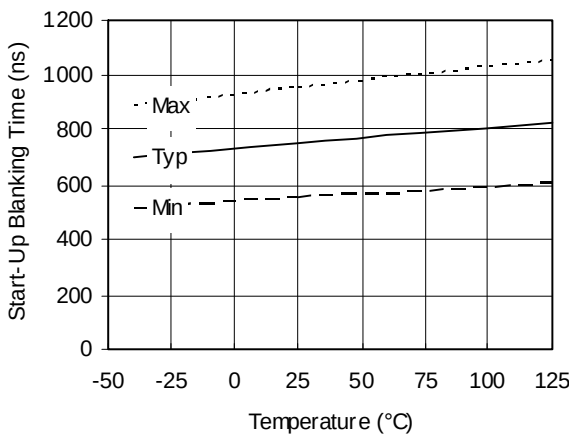


Figure 10A. Start-Up Blanking Time vs. Temperature

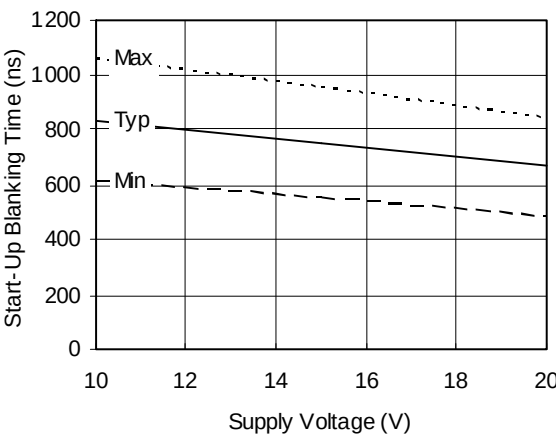


Figure 10B. Start-Up Blanking Time vs. Voltage

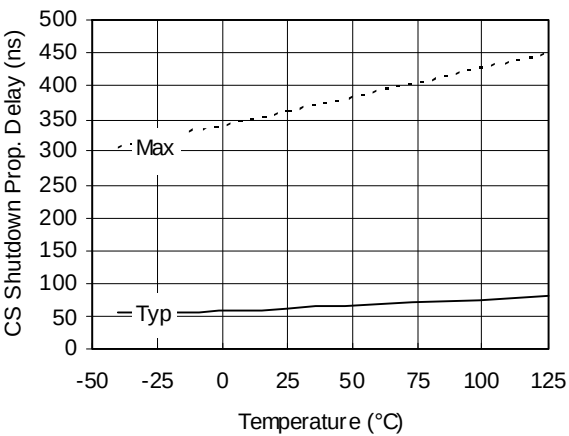


Figure 11A. CS Shutdown Prop. Delay vs. Temperature

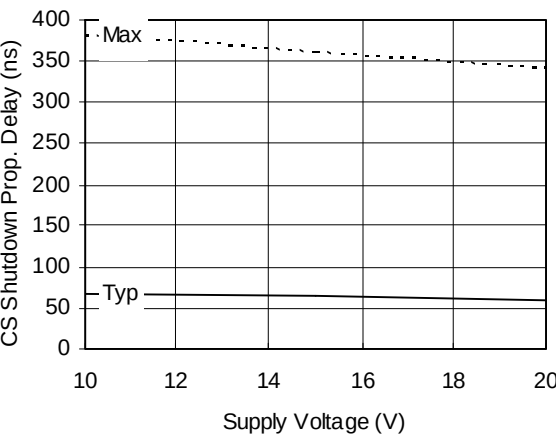


Figure 11B. CS Shutdown Prop. Delay vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

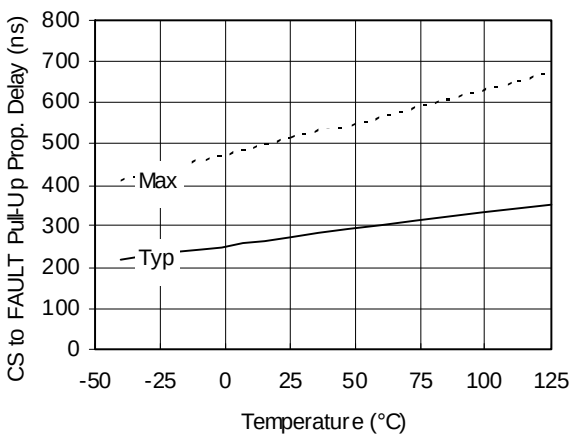


Figure 12A. CS to FAULT Pull-Up Prop. Delay vs. Temperature

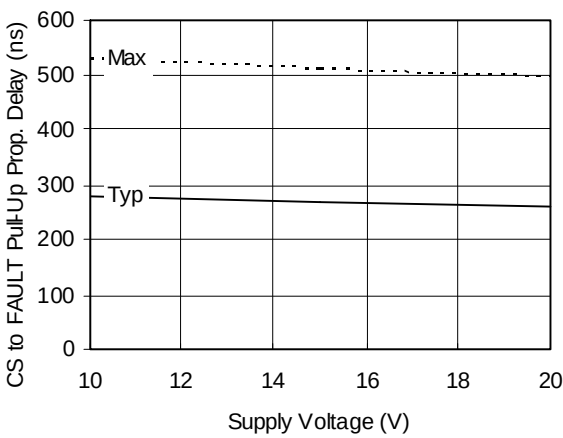


Figure 12B. CS to FAULT Pull-Up Prop. Delay vs. Voltage

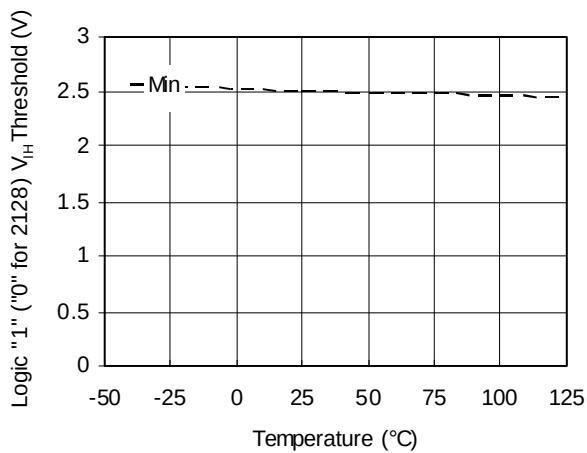


Figure 13A. Logic "1" ("0" for 2128) V_{IH} Threshold vs. Temperature

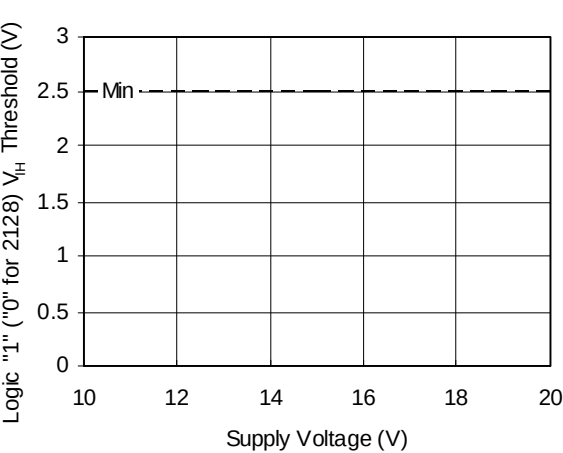


Figure 13B. Logic "1" ("0" for 2128) V_{IH} Threshold vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

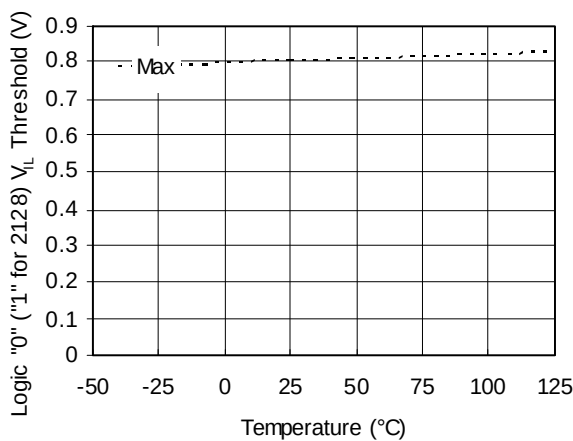


Figure 14A. Logic "0" ("1" for 2128) V_{IL} Threshold vs. Temperature

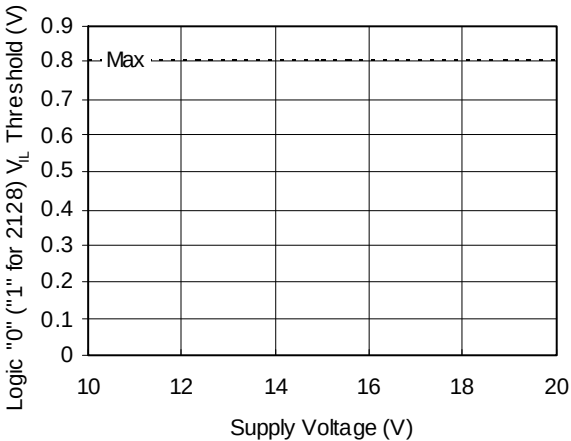


Figure 14B. Logic "0" ("1" for 2128) V_{IL} Threshold vs. Voltage

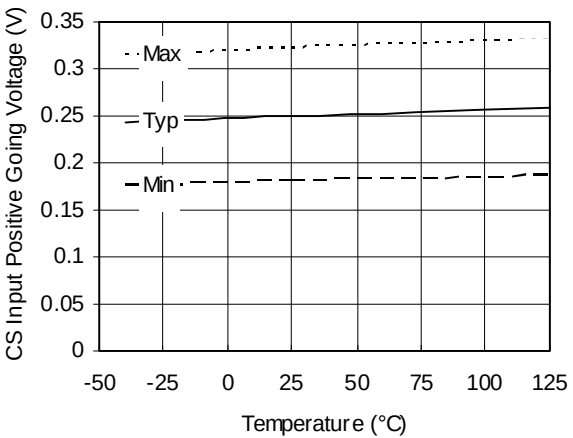


Figure 15A. CS Input Positive Going Voltage vs. Temperature

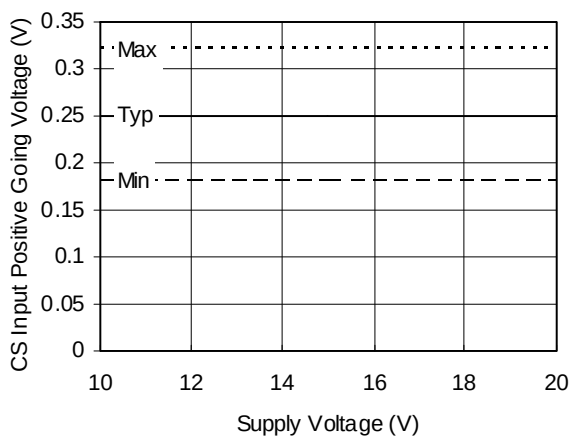


Figure 15B. CS Input Positive Going Voltage vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

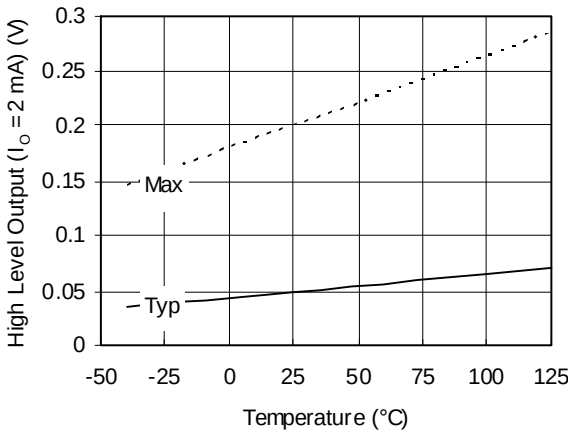


Figure 16A. High Level Output ($I_o = 2\text{ mA}$) vs. Temperature

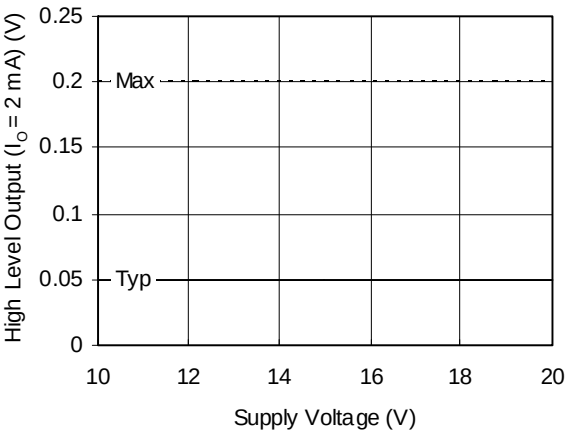


Figure 16B. High Level Output ($I_o = 2\text{ mA}$) vs. Voltage

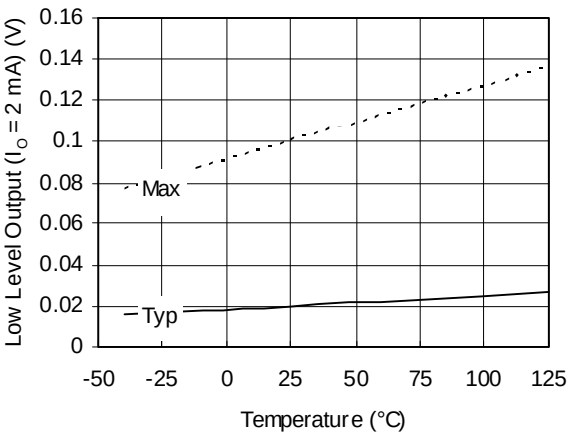


Figure 17A. Low Level Output ($I_o = 2\text{ mA}$) vs. Temperature

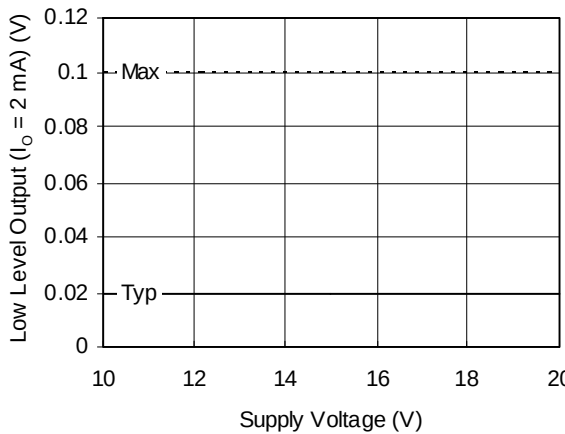


Figure 17B. Low Level Output ($I_o = 2\text{ mA}$) vs. Voltage



IRS212(7, 71, 8, 81)(S)PbF

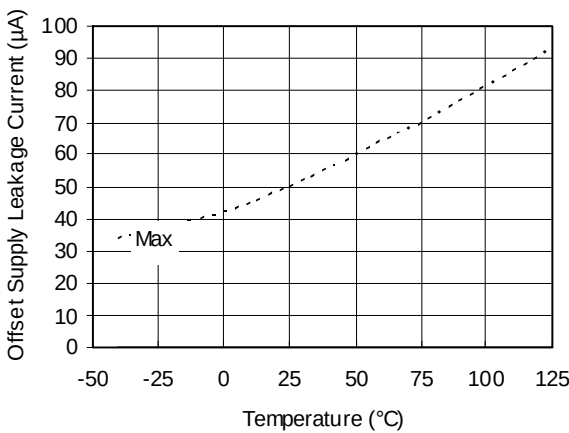


Figure 18A. Offset Supply Leakage Current vs. Temperature

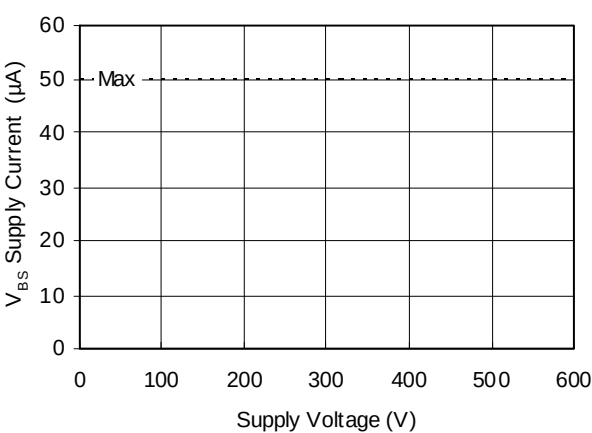


Figure 18B. High-Side Floating Well Offset Supply Leakage vs. Voltage

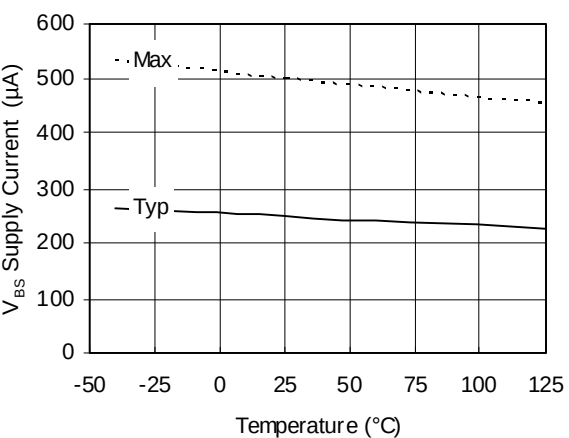


Figure 19A. V_{BS} Supply Current vs. Temperature

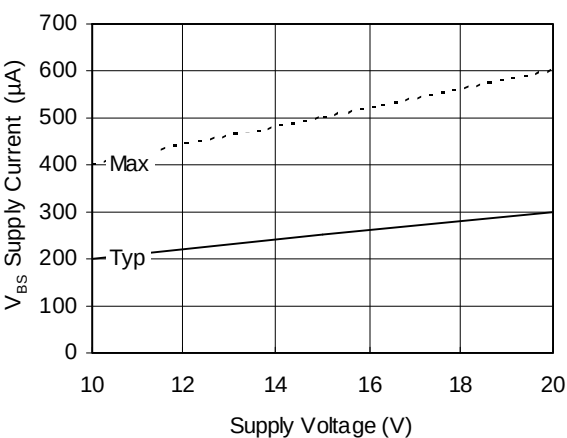


Figure 19B. V_{BS} Supply Current vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

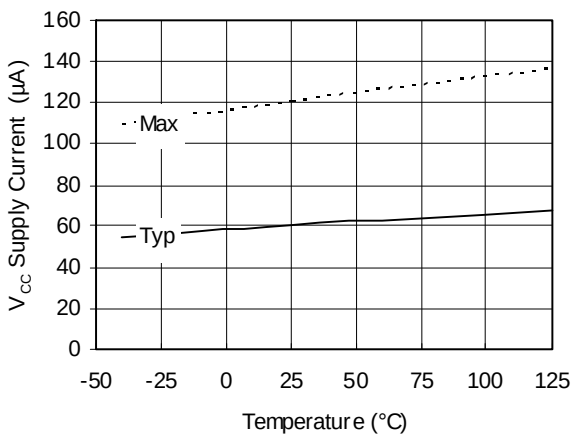


Figure 20A. V_{CC} Supply Current vs. Temperature

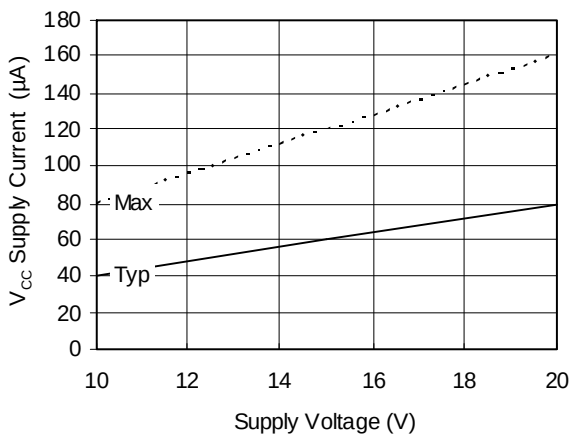


Figure 20B. V_{CC} Supply Current vs. Voltage

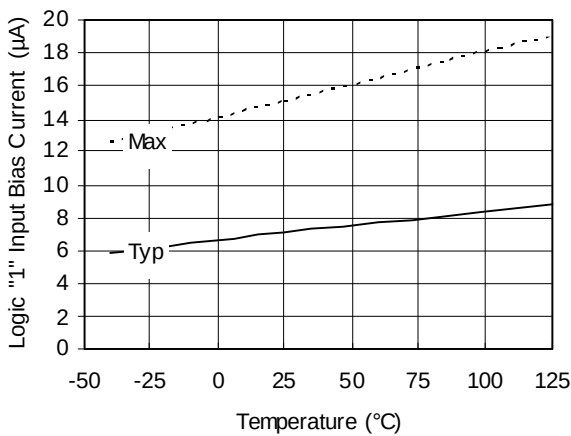


Figure 21A. Logic "1" Input Bias Current vs. Temperature

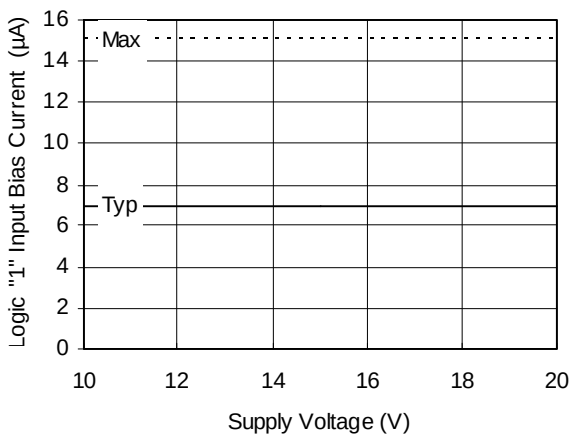


Figure 21B. Logic "1" Input Bias Current vs. Voltage



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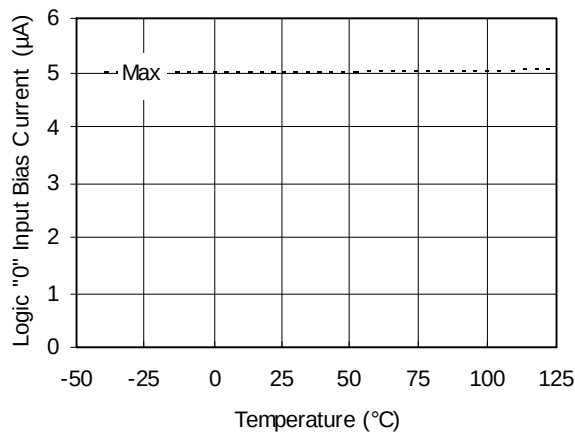


Figure 22A. Logic "0" Input Bias Current vs. Temperature

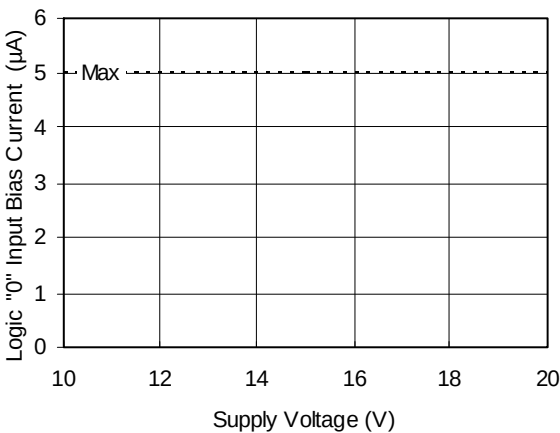


Figure 22B. Logic "0" Input Bias Current vs. Voltage

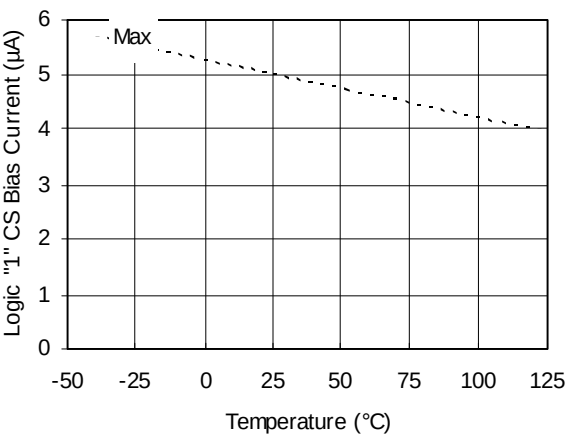


Figure 23A. Logic "1" CS Bias Current vs. Temperature

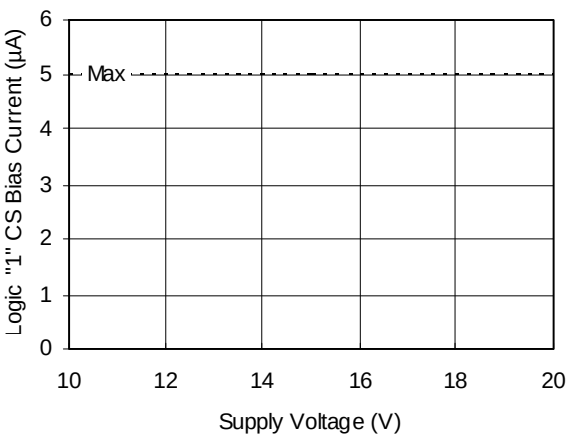


Figure 23B. Logic "1" CS Bias Current vs. Voltage



IRS212(7, 71, 8, 81)(S)PbF

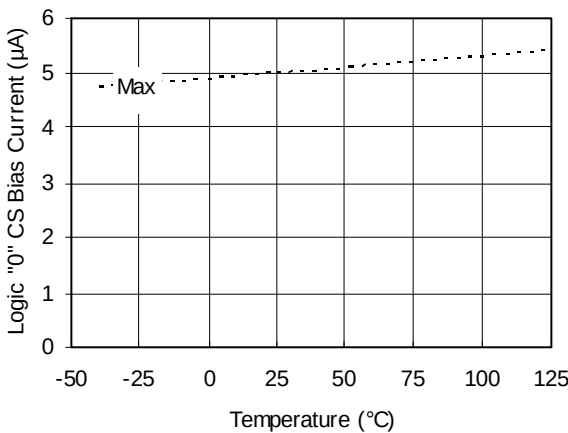


Figure 24A. Logic "0" CS Bias Current vs. Temperature

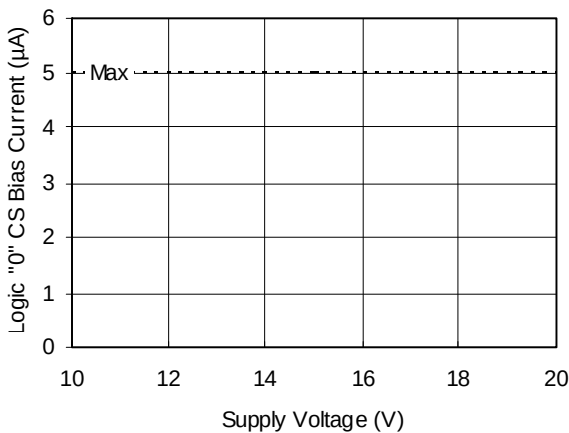


Figure 24B. Logic "0" CS Bias Current vs. Voltage

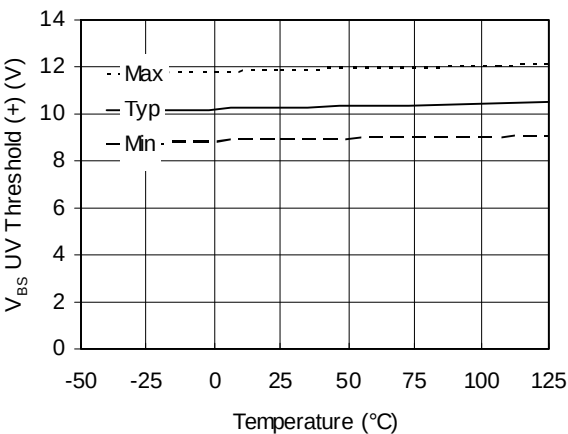


Figure 25A. V_{BS} UV Threshold (+) vs. Temperature

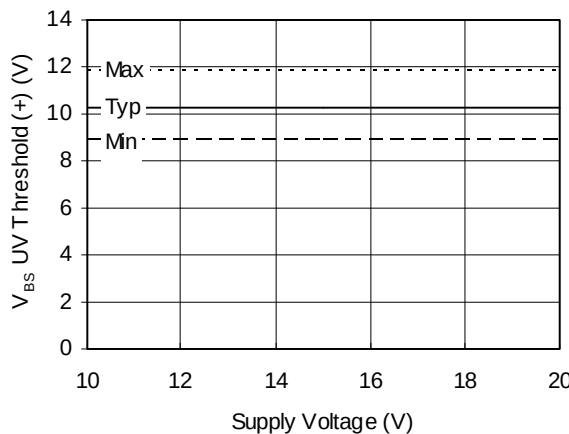


Figure 25B. V_{BS} UV Threshold (+) vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

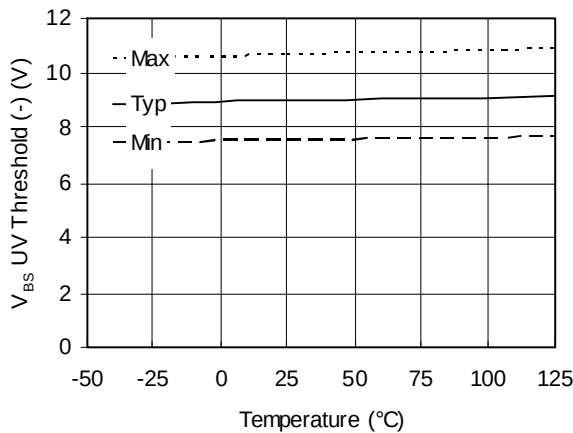


Figure 26A. V_{BS} UV Threshold (-) vs. Temperature

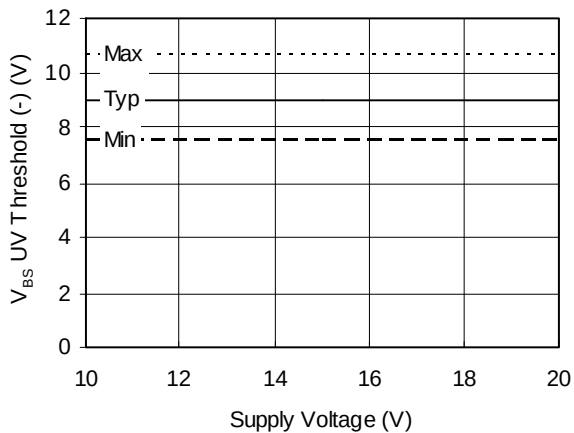


Figure 26B. V_{BS} UV Threshold (-) vs. Voltage

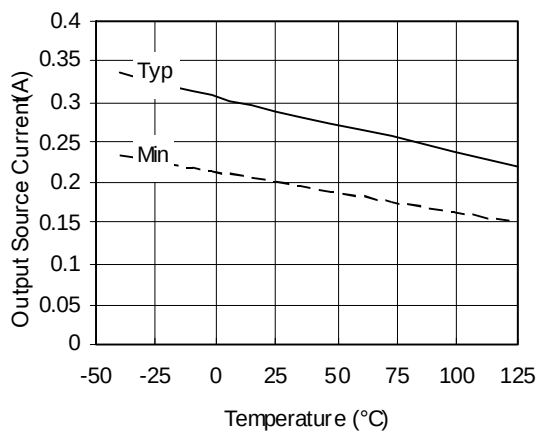


Figure 27A. Output Source Current vs. Temperature

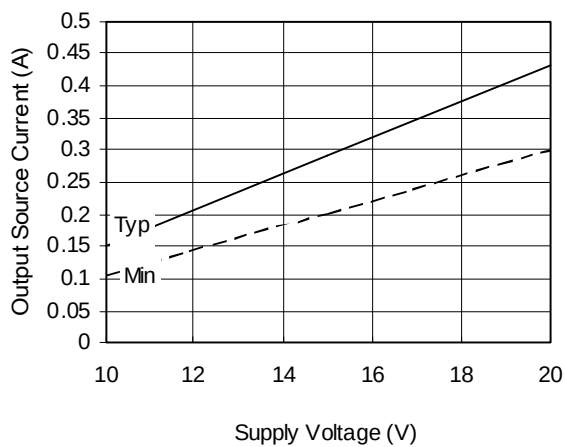


Figure 27B. Output Source Current vs. Voltage

IRS212(7, 71, 8, 81)(S)PbF

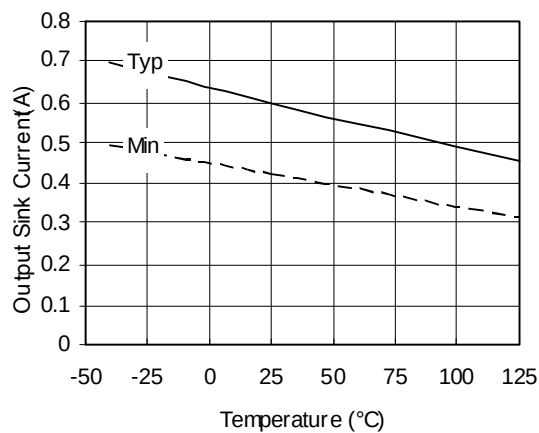


Figure 28A. Output Sink Current vs. Temperature

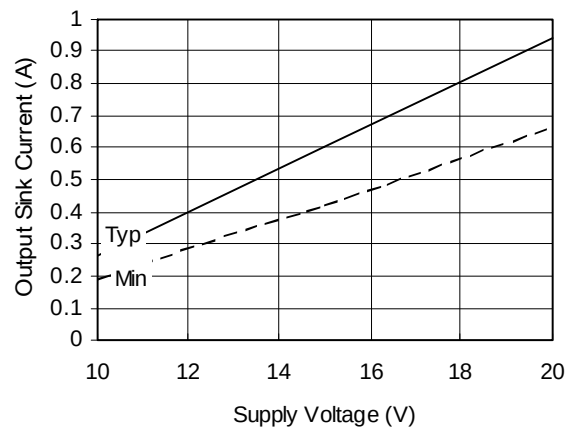
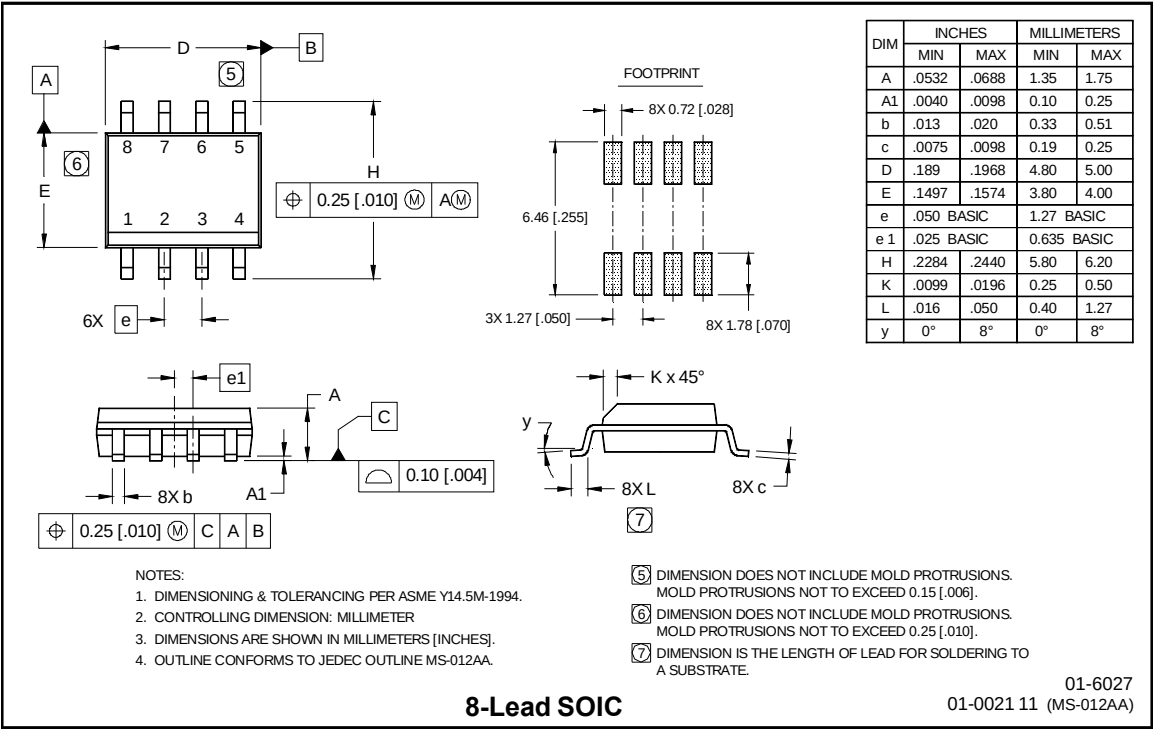
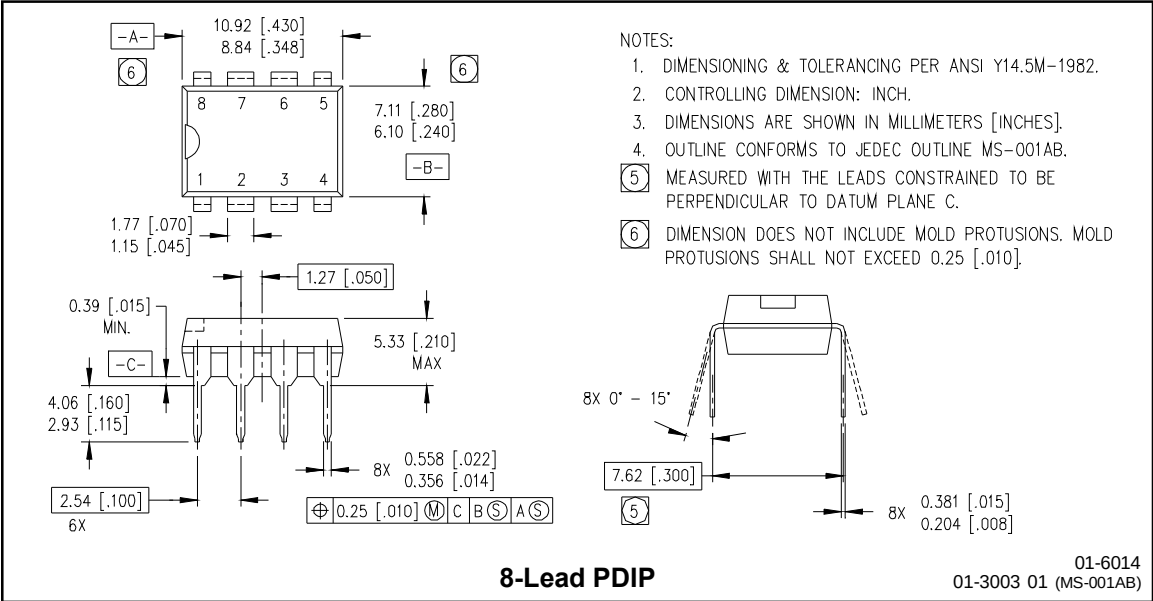


Figure 28B. Output Sink Current vs. Voltage

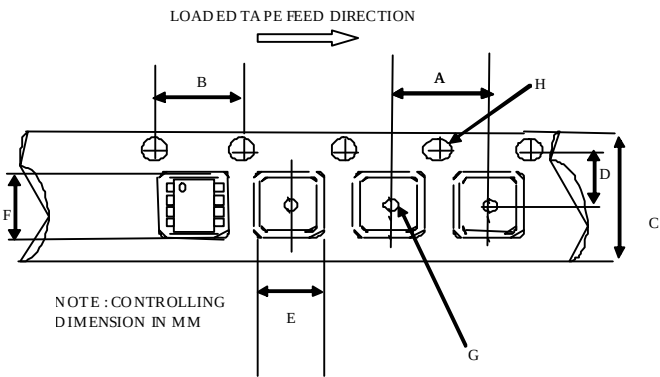
IRS212(7, 71, 8, 81)(S)PbF

Case outlines

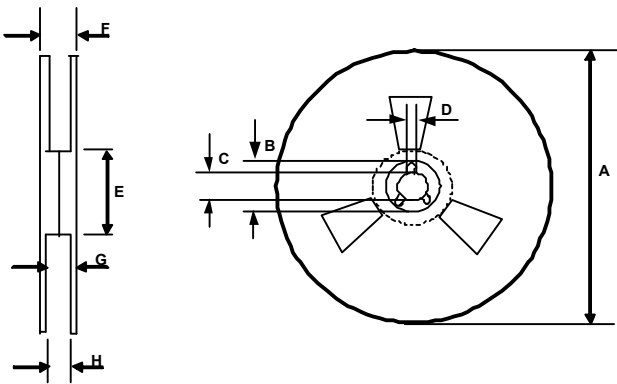


IRS212(7, 71, 8, 81)(S)PbF

Tape & Reel
8-lead SOIC

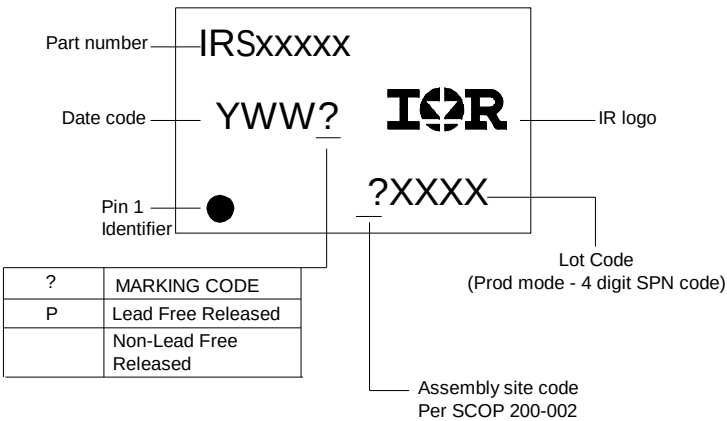


Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

LEADFREE PART MARKING INFORMATION



ORDER INFORMATION

- | | |
|--|--|
| 8-Lead PDIP IRS2127PbF | 8-Lead PDIP IRS2128PbF |
| 8-Lead PDIP IRS21271PbF | 8-Lead PDIP IRS21281PbF |
| 8-Lead SOIC IRS2127SPbF | 8-Lead SOIC IRS2128SPbF |
| 8-Lead SOIC IRS21271SPbF | 8-Lead SOIC IRS21281SPbF |
| 8-Lead SOIC Tape & Reel IRS2127STRPbF | 8-Lead SOIC Tape & Reel IRS2128STRPbF |
| 8-Lead SOIC Tape & Reel IRS21271STRPbF | 8-Lead SOIC Tape & Reel IRS21281STRPbF |